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Spintronic and electrochromic device based on Li-intercalated transition-metal doped anatase TiO_2

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We have explored the effects of the Li intercalation on the electronic and magnetic properties of transition-metal (TM) doped anatase TiO_2. By Li intercalation, Mn-doped TiO_2 exhibits the insulator to metal transition. On the other hand, Li-intercalated Fe-doped TiO_2 has the insulating ground state for low concentration of Li/Ti=0.067, but the metallic ground state for high concentration of Li/Ti=0.133. We discuss the n-type carrier induced ferromagnetism in Li-intercalated TM-doped anatase TiO_2. Based on the Li-intercalated TM-doped anatase TiO_2, we propose a potential spintronic and electrochromic device controlled by the electric-field.

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Spintronics, namely spin-based electronics, is a new generation of microelectronics which utilizes both charge and spin degrees of freedom of carriers. Dilute magnetic semiconductors (DMSs) are expected to play a vital role in spintronics due to easy integration into existing semiconductor devices. Ideal DMS must satisfy such conditions as high Curie temperature (T_C) above room temperature and easy incorporation of p- and n-type dopants. So far, two types of Mn-doped DMS families have been investigated : II-VI (CdTe and ZnSe) [1] and III-V (GaAs) [2] zinc-blende compounds. Especially, the ferromagnetic (FM) behavior with $T_C \sim 110K$ of Mn-doped GaAs attracts great attention, and it has been suggested that delocalized holes mediate the FM interaction between Mn spins [3].

It has been recently reported that Co-doped anatase TiO_2 film ($Ti_{1-x}Co_xO_2$) shows the ferromagnetism even above room temperature. $Ti_{1-x}Co_xO_2$ films were fabricated by means of the pulsed-laser-deposition [4] or the oxygen-plasma-assisted [5] molecular-beam-epitaxy technique. However, still controversial is the issue that the ferromagnetism in this system is an intrinsic DMS property or not. One claim is that Co atoms substitute properly for Ti atoms [4,5,6] and the ferromagnetism is caused by the exchange interaction mediated by the vacancy-induced n-type carriers. Another is that Co atoms form nano-clusters, resulting in the high T_C ferromagnet [7,8]. The other claim is that Co atom incorporates in the interstitial position or forms Co-Ti-O complexes [9]. It is also reported that the as-grown film has coexisting contributions from Co metal clusters and matrix-incorporated Co, but that the high temperature heat treatment enhances the matrix-incorporated Co contribution drastically [10].

Independently of the DMS project, Li intercalation in anatase TiO_2 has been studied extensively for possible uses in high energy density batteries, electrochromic, and solar-cell devices [11,12,13,14]. It is possible to intercalate Li atoms in anatase TiO_2 up to the Li/Ti ratio of ~ 0.7. There is an indication that the intercalation does not occur uniformly throughout each crystallite [15]. Further, there seem to exist two phases: the Li-poor anatase phase and the Li-rich orthorhombic phase [16,17]. The insulator to metal transition is observed for the Li/Ti ratio of ~ 0.3 [15]. Interestingly, the magnetic susceptibility is observed to be proportional to the Li/Ti ratio in the Li-intercalated anatase TiO_2 with the measured localized moment of $\sim 0.004\ \mu_B$ per Ti.

Motivated by the easy Li intercalation into anatase TiO_2, we have explored the magnetic properties of transition-metal (TM) doped TiO_2 with intercalating Li. To this end, we have investigated electronic structures of Li-intercalated $Ti_{0.9375}M_{0.0625}O_2$ (M=Mn, Fe). We have found that both Mn- and Fe-doped TiO_2 with sufficient intercalated Li concentration have metallic and ferromagnetic ground states, implying that n-type carriers produced by Li intercalation induce the ferromagnetism.

We have employed the linearized muffin-tin orbital (LMTO) band method in the local-spin-density approximation (LSDA). The space group of anatase structure is tetragonal $I4_1/amd$. The anatase TiO_2 is composed of stacked edge-sharing octahedrons formed by six O anions. Ti atoms are in the interstitial sites of octahedrons that are distorted with different bond lengths between the apical (1.979 $\AA$) and the equatorial (1.932 $\AA$) Ti-O bond and with the Ti-O-Ti angle 156.3^o. For $Ti_{0.9375}M_{0.0625}O_2$, we have considered a supercell containing sixteen formula units in the primitive unit cell by replacing one Ti by M atoms ($Ti_{15}M_1O_{32}$: $a = b = 7.570, c = 9.514$ Å). Sixteen empty spheres are considered in the interstitial sites to enhance the packing ratio for the LMTO band calculation. To simulate the Li intercalation, we replaced one (corresponds to Li/Ti=0.067) or two (Li/Ti=0.133) interstitial empty spheres by Li atoms.

We have studied before electronic structures of TM doped anatase $Ti_{1-x}M_xO_2$ (M=Mn, Fe, Co, Ni) without Li intercalation [18]. Using the LSDA band calculation, we have obtained the *half-metallic* ground states for Fe- and Co-doped cases with the carrier type of mainly Fe and Co $3d$ states, respectively. On the other hand, we have obtained insulating ground states for Mn- and Ni-doped cases. Ni-doped TiO_2 was found to be nonmagnetic. We have also studied Li intercalation effects on

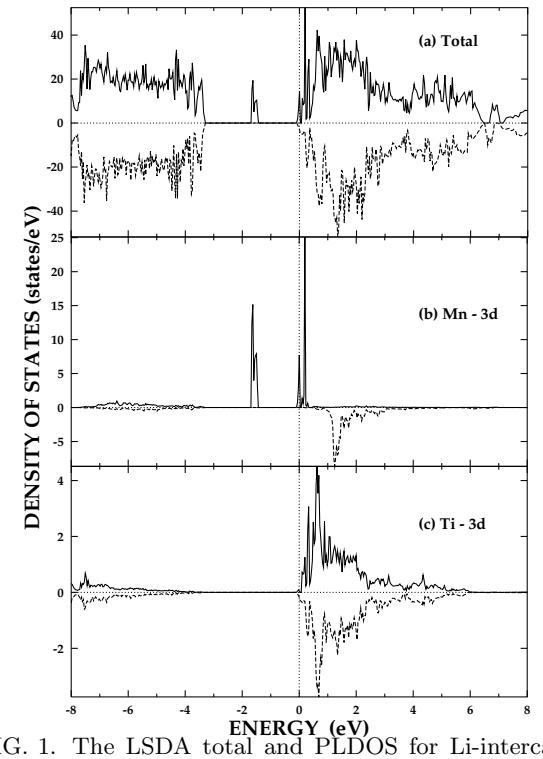

FIG. 1. The LSDA total and PLDOS for Li-intercalated $Ti_{0.9375}Mn_{0.0625}O_2$ (Li/Ti=0.067).

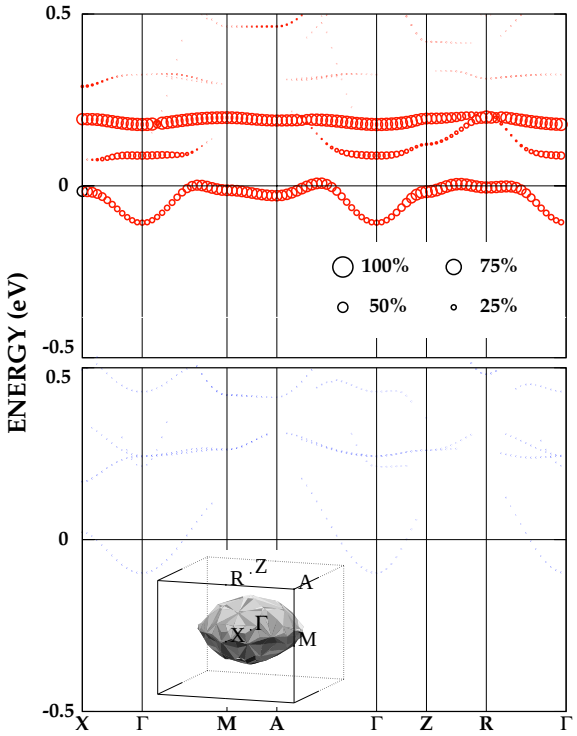

FIG. 2. Band structure of Li-intercalated $Ti_{0.9375}Mn_{0.0625}O_2$ (Li/Ti=0.067) near the Fermi level. The size of circle represents the amount of Mn 3d component in the wave function (the upper panel for the majority and the lower for the minority spin band). In the inset of the lower panel, the Fermi surface for the minority spin band is given.

the electronic and magnetic properties of both undoped and Co-doped anatase TiO_2 [19]. What we have found for undoped TiO_2 was that the n-type carriers produced by the Li intercalation fill Ti 3d conduction band so as to induce small magnetic moments at Ti sites. In contrast, Li-intercalated Co-doped TiO_2 becomes nonmagnetic and insulating, because the produced n-type carriers fill up the low-spin Co 3d states located in the energy gap region. Hence the Li intercalation was detrimental to stabilizing the magnetic state in Co-doped TiO_2. These features, however, suggested that some other TM-doped anatase TiO_2 with TM of high-spin configuration would have carrier induced ferromagnetism through the Li intercalation.

Now let us study the Li intercalation effects in $Ti_{0.9375}Mn_{0.0625}O_2$. Figure 1 provides the LSDA density of states (DOS) for the FM phase of $Ti_{0.9375}Mn_{0.0625}O_2$ with Li/Ti=0.067 [20]. We have obtained metallic ground state, contrary to the non-intercalated Mn-doped TiO_2 which has an insulating ground state. The energy band gap between O 2p and Ti 3d states is estimated to be $\sim$ 3.2 eV, which is reduced from $\sim$ 4 eV estimated for the non-intercalated case. The Mn 3d projected local density of states (PLDOS) indicates the high-spin state of Mn, that is, the exchange splitting between t_{2g} states is larger than the crystal-field splitting between t_{2g} and e_g states. Most of occupied Mn 3d (t_{2g}) states are located in the energy gap region, whereas the empty Mn 3d states are shifted up and hybridized with Ti 3d conduction band. Note that, for the non-intercalated case, both the occupied t_{2g} and the empty e_g states were in the energy gap region far below the Ti 3d conduction band. According to the rigid band model, the extra n-type carriers produced by Li intercalation would fill the empty Mn e_g majority spin states first. Figure 1, however, indicates that the extra electrons fill not only Mn e_g majority spin states but also Ti 3d conduction band, indicating that the simple rigid band concept does not work here. It happens because the extra carriers produced by Li intercalation are localized at Ti sites near the intercalated Li. Due to this localization, Mn e_g majority spin states are pushed up above the Ti 3d conduction band bottom and so only slightly filled. The magnetic moment of Mn ion is 3.43 μ_B, and the total magnetic moment is 3.74 μ_B. With Li intercalation, magnetic moments of Ti ions are a bit enhanced as compared to the non-intercalated case.

Figure 2 shows the band structure of Li-intercalated $Ti_{0.9375}Mn_{0.0625}O_2$ with Li/Ti=0.067 near the Fermi level E_F. The size of circle represents the amount of Mn 3d component in the wave function. It is seen that the majority spin states near E_F are mostly of Mn 3d states, while the minority spin states near E_F correspond mainly to Ti 3d conduction band states with fairly large band dispersion. Thus Mn 3d states are nearly half-metallic

and the flat Mn 3d states suggest that they are rather localized [21]. Half-metallic Mn 3d states near E_F together with the localized Mn t_{2g} states far below E_F suggest that the double-exchange (DE) mechanism would be operative to yield the FM ordering of Mn spins [18].

On the other hand, the localized nature of Mn 3d states and the dispersive Ti 3d conduction band carriers are reminiscent of Mn-doped GaAs in which As 4p hole carriers seem to mediate the Ruderman-Kittel-Kasuya-Yosida (RKKY)-type exchange interaction [22,23,24]. The difference from Mn-doped GaAs is the type of conduction band carriers which is n-type in the present case. With the information of the Fermi surface wave vector k_F of the conduction band, one can derive the magnetic ground state of the system in the RKKY formalism, That is, if the relation $2k_F R_{\rm MM} < 4.5$ ($R_{\rm MM}$: nearest distance between Mn spins) is satisfied, the FM ordering of Mn spins would be stabilized [25]. As shown in the inset of Fig. 2, the minority spin band structure has an oblate sphere-like Fermi surface centered at Γ. One can measure k_F's directed from Γ to some symmetry points in the irreducible Brillouin zone [26]. The longest k_F is $k_F^{\Gamma-X}$, while the shortest one is $k_F^{\Gamma-Z}$. Then, with $R_{\rm MM}$= 7.57 Å, one obtains $2k_F R_{\rm MM} = 4.63$ and 2.96 for Γ - X and Γ - Z directions, respectively. However, besides $k_F^{\Gamma-X}$, all other k_F's give rise to $2k_F R_{\rm MM}$ less than 4.5, suggesting that the FM interaction is dominant in the RKKY interaction mediated by the n-type conduction band carriers of Ti 3d states. Therefore, it is expected that, in Li-intercalated $Ti_{0.9375}Mn_{0.0625}O_2$, the FM interaction between Mn spins is reinforced by the combined effects of the DE and RKKY interactions.

For more Li-intercalated $Ti_{0.9375}Mn_{0.0625}O_2$ with Li/Ti=0.133, we have also obtained magnetic and metallic ground state. More extra electrons fill both Mn and Ti 3d states. Compared to the Li/Ti=0.067 case, the total magnetic moment is reduced to 3.6 μ_B, while Mn has nearly the same value, 3.41 μ_B. The reduced total magnetic moment originates from lowered Mn 3d DOS at E_F which diminishes the spin-polarized hybridization between Mn and neighboring atoms. As mentioned above, the observed FM state in Co-doped TiO_2 is questioned whether it is an intrinsic DMS property or not. Once the FM state is observed in Mn-doped TiO_2, it can be considered as intrinsic, because Mn or Mn-oxide clusters, if they were formed in anatase TiO_2, would have the AFM ground state. Therefore, to get the direct evidence of DMS property in TiO_2, it is desirable to fabricate Mn-doped TiO_2 with varying the intercalated Li concentration.

Next we have examined electronic structures of Li-intercalated Fe-doped TiO_2: $Ti_{0.9375}Fe_{0.0625}O_2$ with Li/Ti=0.067 and 0.133. For Li/Ti=0.067 case, we have obtained the insulating and magnetic ground state (see the inset of Fig.3). This is again in contrast to non-intercalated Fe-doped TiO_2 which is half-metallic [18]. The electron carriers produced by Li intercalation fill up

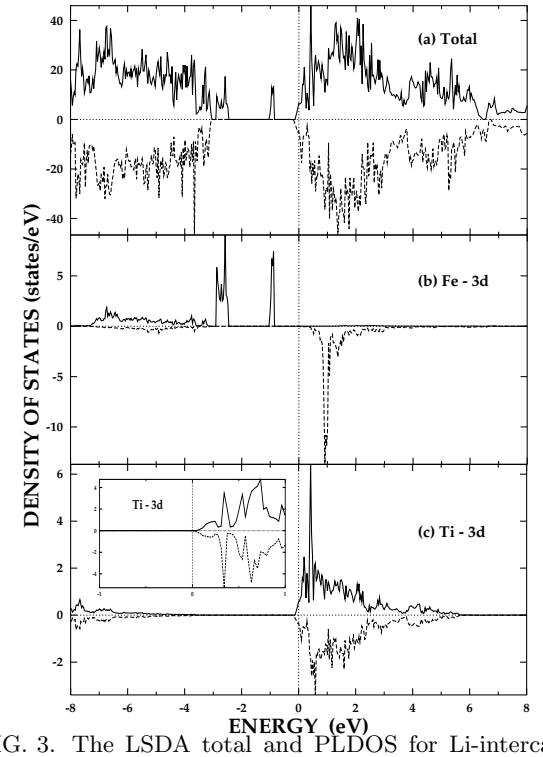

FIG. 3. The LSDA total and PLDOS for Li-intercalated $Ti_{0.9375}Fe_{0.0625}O_2$ with Li/Ti=0.133. Inset shows the insulating nature of Ti 3d PLDOS near E_F for Li/Ti=0.067.

the Fe e_g majority spin states which was half-filled for the non-intercalated case. The empty Fe 3d minority spin states are shifted up above Ti 3d conduction band bottom, as in the Mn-doped case (Fig.3). The energy band gap between O 2p and Ti 3d states is estimated to be $\sim$ 3.0 eV which is similar to that of Mn-doped case. Total magnetic moment is 5 μ_B, which comes mainly from Fe local magnetic moment of 4.31 μ_B.

Figure 3 presents results for more Li-intercalated Fe-doped TiO_2 with Li/Ti=0.133. In this case, we have obtained the metallic and magnetic ground state. The metallic ground state results from more electron carriers produced by more intercalated Li concentration. The states near E_F are mostly of Ti 3d character. This feature is different from the Mn-doped case having both Ti and Mn 3d characters near E_F. It is expected that the RKKY-type interaction works here too, that is, n-type carriers of Ti 3d states mediate the magnetic interaction between Fe local magnetic moments. Note, however, that the Ti conduction band shows little spin polarization at E_F ($\sim$ 20.5%), and so this case is different from Mn-doped GaAs which has the 100% spin polarization at E_F. Total magnetic moment is a bit reduced to 4.85 μ_B, but Fe local moment 4.31 μ_B is nearly the same. The reduced total magnetic moment seems due to metallic phase, which results in the enhanced AFM interaction between Fe and oxygen ions.

On the basis of above findings, we propose a new spin-

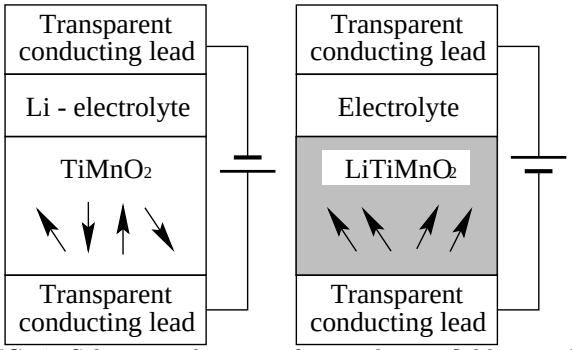

FIG. 4. Schematic diagrams for an electric-field controlled nonvolatile FM and electrochromic multifunctional device

tronic device which can be controlled by the electric-field. Figure 4 shows a schematic diagram of device made of Mn-doped TiO_2 operating by the voltage bias. Li ions are supplied from the Li electrolyte. The left figure represents the case of no Li intercalation with applied (+) voltage bias on the bottom lead. Then it corresponds to non-intercalated Mn-doped TiO_2 which would not have the long-range magnetic ordering (nonmagnetic: NM). The right figure represents the case of Li intercalation with applied (−) voltage bias on the bottom lead. Now, due to carriers produced by Li intercalation, Mn-doped TiO_2 film would have the FM ordering. In this way, it is possible to control the magnetic ordering by the electric-field. Even after removing bias, the magnetic ordering is maintained, unless the reversed bias is applied. So the proposed device has the non-volatile magnetic ordering. The non-volatile property of this device is distinct from the previously demonstrated Mn-doped III-V device also controlled by the electric-field [27]. In addition, if the optical property is not affected by doped TM elements as in the case of Co-doped TiO_2 [4], one can fabricate the multi-functional device with variable magnetic and electrochromic properties:

$$Ti_{1-x}Co_xO_2 + yLi^+ + ye^- \rightleftharpoons Li_yTi_{1-x}Co_xO_2$$
(transparent FM) (colored NM)

$$Ti_{1-x}\begin{pmatrix} Mn \\ Fe \end{pmatrix}_x O_2 + yLi^+ + ye^- \rightleftharpoons Li_yTi_{1-x}\begin{pmatrix} Mn \\ Fe \end{pmatrix}_x O_2$$
(transparent NM) (colored FM)

In this way, an electric-field controlled spintronic and electrochromic device can be realized in the Li-intercalated TM-doped anatase TiO_2 system.

In conclusion, we have obtained ferromagnetic ground state for Li-intercalated Mn-doped TiO_2 with the n-type carriers of Ti $3d$ states. Mn ions have the high spin states with 3.43 and 3.41 μ_B spin moments for Li/Ti=0.067 and 0.133, respectively. We have also obtained magnetic ground state for Li-intercalated Fe-doped TiO_2. As the intercalated Li concentration increases, the electronic structure changes from insulating to metallic nature. Fe ions have the high spin states with 4.31 μ_B spin moment for both cases. Our results suggest that the DMSs of Mn- and Fe-doped anatase TiO_2 can be synthesized by Li intercalation. Based on our findings, we propose a novel non-volatile spintronic and electrochromic multifunctional device which can be controlled by the electric-field.

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[1] J. K. Furdyna and J. Kossut, *DMSs*, **25** of Semiconductor and Semimetals, Academic Press, New York, (1988).
[2] H. Ohno *et al.*, Appl. Phys. Lett. **69**, 363 (1996).
[3] T. Dietl *et al.*, Phys. Rev. B **63**, 195205 (2001).
[4] Y. Matsumoto *et al.*, Science **291**, 854 (2001).
[5] S. A. Chambers *et al.*, Appl. Phys. Lett **79**, 3467 (2001).
[6] S. A. Chambers *et al.*, cond-mat/0208315.
[7] D. H. Kim *et al.*, Appl. Phys. Lett **81**, 2421 (2002).
[8] J. Y. Kim *et al.*, Phys. Rev. Lett. (2002).
[9] J. R. Simpson *et al.*, cond-mat/0205626.
[10] S. R. Shinde *et al.*, cond-mat/0203576.
[11] D. O'Hare, in *Inorganic Materials*, edited by D. W. Bruce and D. O'Hare, John Wiley & Sons, New York, (1996).
[12] T. Ohzuku and T. Hirai, Electrochim. Acta **27**, 1263 (1982).
[13] B. O'Regan and M. Grätzel, Nature **353**, 737 (1991).
[14] M. P. Cantão, J. I. Cisnerso, and R. M. Torresi, Thin Solid Films **259**, 70 (1995).
[15] V. Luca *et al.*, Chem. Mater. **13**, 796 (2001).
[16] M. Wagemaker *et al.*, Nature **419**, 397 (2002).
[17] M. V. Koudriachova *et al.*, Phys. Rev. Lett. **86**, 1275 (2001).
[18] M. S. Park, S. K. Kwon, and B. I. Min, Phys. Rev. B **65**, 161201 (2002).
[19] M. S. Park *et al.*, to appear in Physica B.
[20] We have compared the LSDA total energies of the FM and AFM configurations of TM (Mn, Fe) spins for Li-intercalated $Ti_{0.875}TM_{0.125}O_2$ with Li/Ti=0.143. The energy differences between two configurations are found to be negligible within the numerical precision. But, for Fe-doped case, the insulating state prefers the AFM configuration of Fe spins.
[21] The LSDA+U (U = 3.0 eV) band calculation yields the further splitting in the majority spin e_g states near E_F. But the lower pinned states at E_F are not changed much.
[22] M. Shirai *et al.*, J. Magn. Magn. Mater. **177**, 1383 (1998).
[23] H. Akai, Phys. Rev. Lett. **81**, 3002 (1998).
[24] J. H. Park, S. K. Kwon, B. I. Min, Physica B **281**, 703 (2000).
[25] M. A. Ruderman and C. Kittel, Phys. Rev. **96**, 99 (1954).
[26] We have checked that k_F's are almost the same for both FM and AFM configurations of Mn spins. It is because k_F's are determined by dispersive Ti $3d$ states.
[27] H. Ohno *et al.*, Nature **408**, 944 (2000).